

Data Sheet January 2000 File Number 4049.1

150A, 1200V Hyperfast Diode

The RHRU150120 is a hyperfast diode with soft recovery characteristics ($t_{rr} < 100$ ns). It has half the recovery time of ultrafast diodes and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49074.

Ordering Information

PART NUMBER	PACKAGE	BRAND	
RHRU150120	TO-218	RHR150120	

NOTE: When ordering, use the entire part number.

Symbol



Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified

Features

•	Hyperfast with Soft Recovery <100n
•	Operating Temperature
•	Reverse Voltage
	Avalancha Enargy Pated

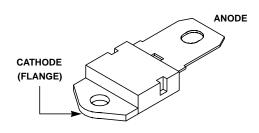
- Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supplier
- · Power Switching Circuits
- · General Purpose

Packaging

SINGLE LEAD JEDEC STYLE TO-218



RHRU150120 UNITS Peak Repetitive Reverse Voltage......VRRM 1200 Working Peak Reverse VoltageV_{RWM} ٧ 1200 DC Blocking VoltageV_R 1200 150 $T_C = 37.5^{\circ}C$ 300 Α (Square Wave, 20kHz) 1500 Α (Halfwave, 1 phase, 60Hz) 375 W

50

-65 to 175

mJ

οС

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 150A	-	-	3.2	V
	I _F = 150A, T _C = 150°C	-	-	2.6	V
I _R	V _R = 1200V	-	-	250	μΑ
	V _R = 1200V, T _C = 150°C	-	-	3.0	mA
t _{rr}	I _F = 1A, dI _F /dt = 200A/μs	-	-	100	ns
	$I_F = 150A$, $dI_F/dt = 200A/\mu s$	-	-	125	ns
t _a	I _F = 150A, dI _F /dt = 200A/μs	-	70	-	ns
t _b	I _F = 150A, dI _F /dt = 200A/μs	-	40	-	ns
Q _{RR}	I _F = 150A, dI _F /dt = 200A/μs	-	460	-	nC
СЈ	V _R = 10V, I _F = 0A	-	420	-	pF
R _{θJC}		-	-	0.4	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b .

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

 Q_{RR} = Reverse recovery charge.

 C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

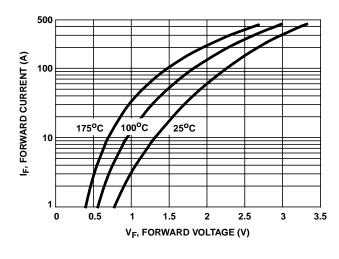


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

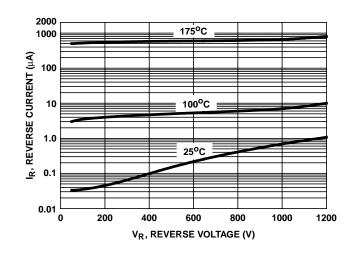


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

250

Typical Performance Curves (Continued)

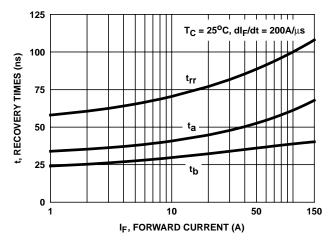
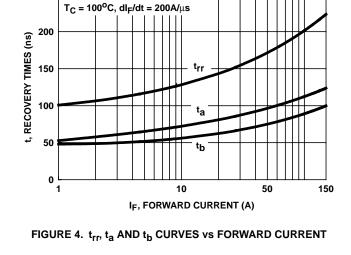


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT



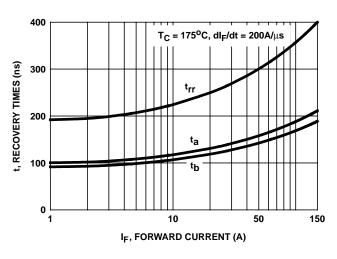


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

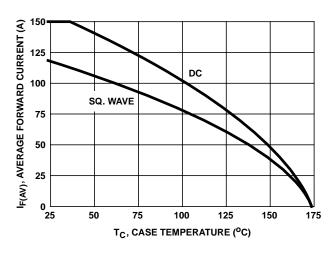


FIGURE 6. CURRENT DERATING CURVE

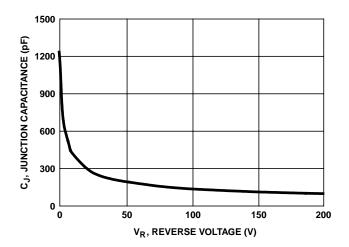


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

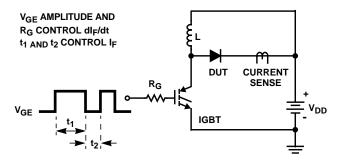


FIGURE 8. t_{rr} TEST CIRCUIT

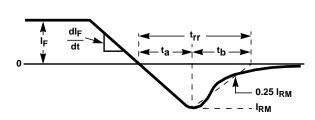


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

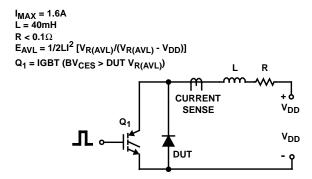


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

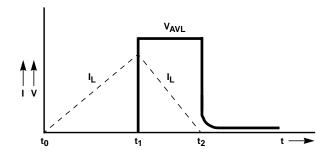


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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